

Features

- * 450W peak pulse power (8/20 μ s)
- * Protects one data or power line
- * Ultra low leakage: nA level
- * Operating voltage: 5V
- * Ultra low clamping voltage
- * Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: ± 30 kV
 - Contact discharge: ± 30 kV
 - IEC61000-4-4 (Lightning) 30A (8/20ns)
- * RoHS Compliant
- * Package: SOD-323
- * Lead Finish: Matte Tin

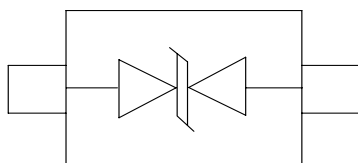
Description

The SD05C is designed to replace multilayer varistors in portable applications such as cell phones, notebook computers and PDA's, using monolithic silicon technology to provide fast response time and ultra low ESD clamping voltage, making this device an ideal solution for protecting sensitive semiconductor components from damage. The SD05C complies with the IEC 61000-4-2 (ESD) standard with ± 15 kV air and ± 8 kV contact discharge. The SD05C is assembled into a lead-free SOD-323 package and will protect one unidi-rectional line. These devices will fit on the same PCB pad area as an 0805 MLV device.

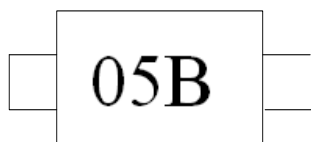
Applications

- * Cellular Handsets and Accessories
- * Personal Digital Assistants
- * Notebooks and Handhelds
- * Portable Instrumentation
- * Peripherals
- * Pagers Peripherals
- * Desktop and Servers

Circuit Diagram



Marking Diagram



Transparent top view

05B:Device Marking Code

Ordering Information

Part Number	Packaging	Reel Size
SD05C	3000/Tape & Reel	7 inch

Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

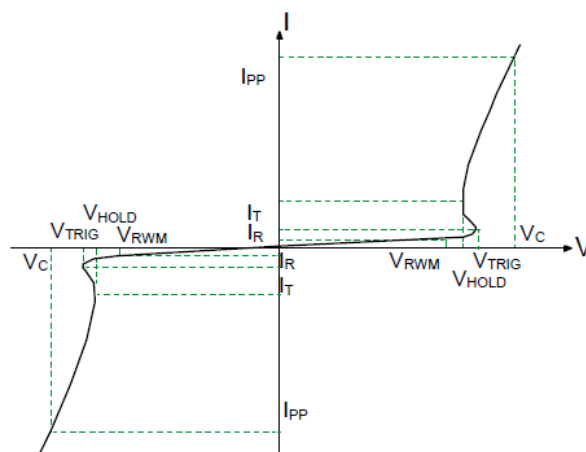
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	450	W
Peak Pulse Current (8/20μs)	IPP	30	A
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	V _{RWM}				5	V
Breakdown Voltage	V _{BR}	I _T = 1mA(Pin1-Pin2)	6.0	7.0	8.0	V
Reverse Leakage Current	I _R	V _{RWM} = 5. 0V(Pin2-Pin1)			0.5	μA
Clamping Voltage	V _C	I _{PP} = 10A (8 x 20μs pulse) (Pin1-Pin2)		9.0	11.0	V
Clamping Voltage	V _C	I _{PP} = 30A (8 x 20μs pulse) (Pin1-Pin2)		12. 0	15.0	V
Junction Capacitance	C _J	V _R = 0V, f = 1MHz (Pin1-Pin2)		60	100	pF

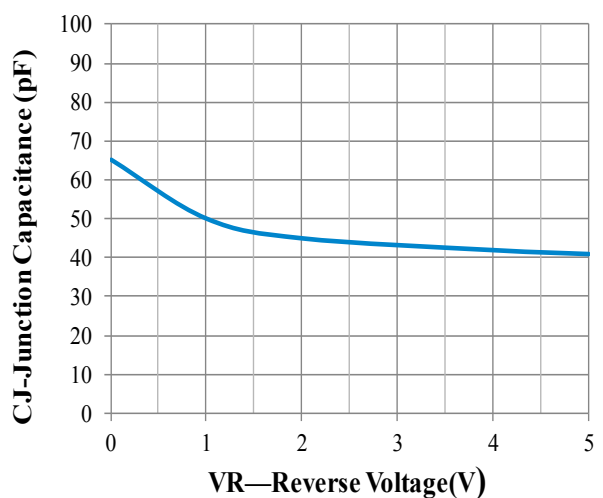
Portion Electronics Parameter

Symbol	Parameter
I _T	Test Current
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @I _C

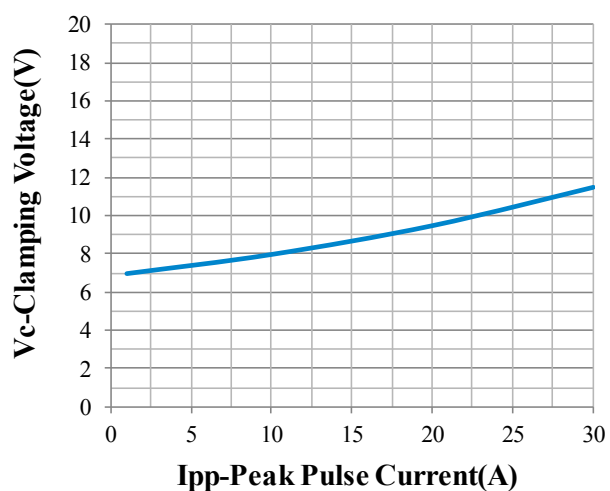




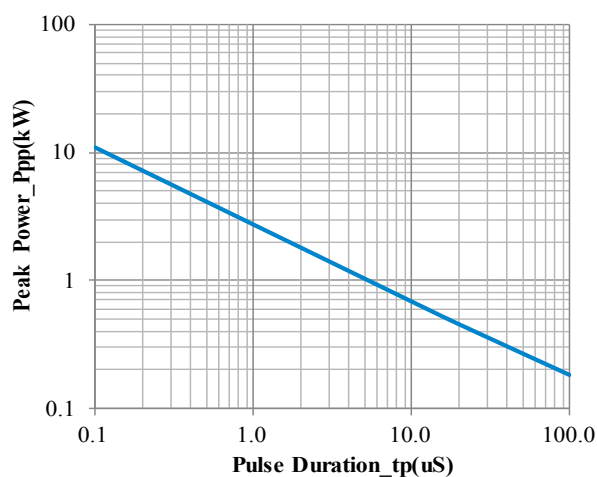
Typical Performance Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise Specified)



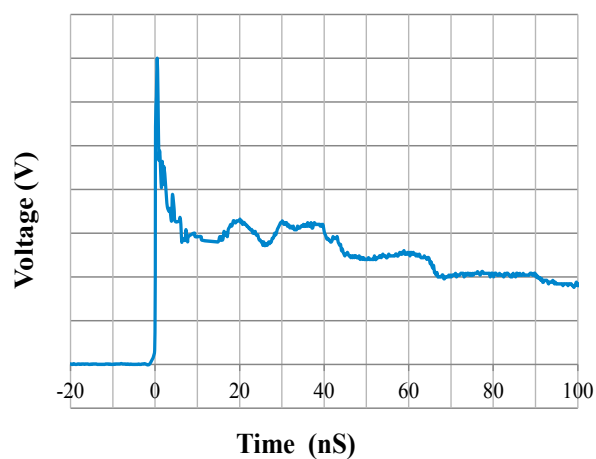
Junction Capacitance vs. Reverse Voltage



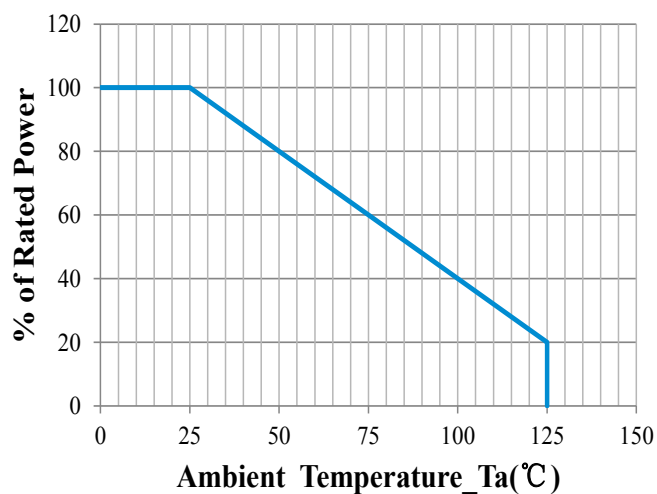
Clamping Voltage vs. Peak Pulse Current



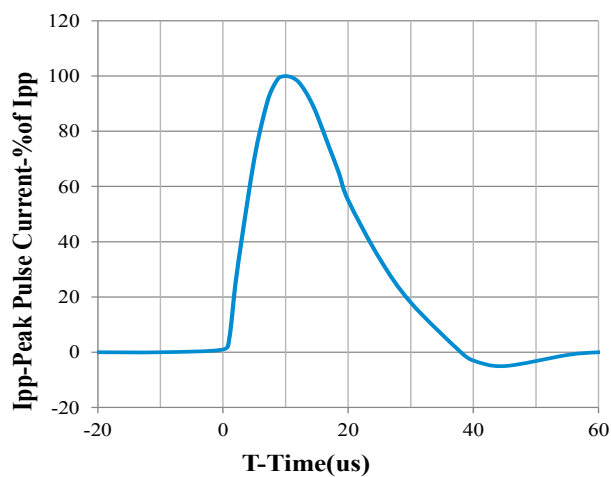
Peak Pulse Power vs. Pulse Time



IEC61000-4-2 Pulse Waveform

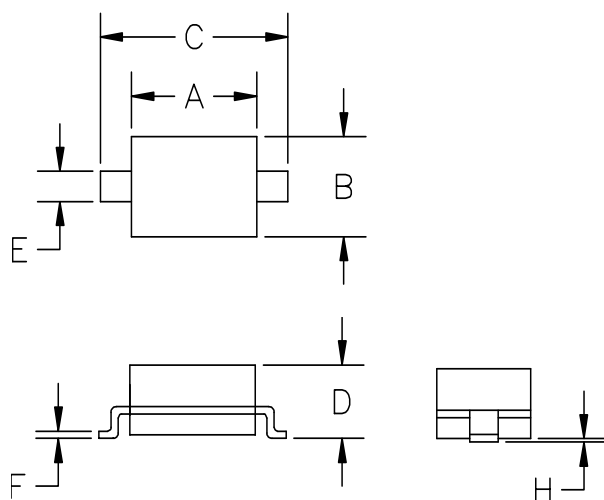


Power Derating Curve



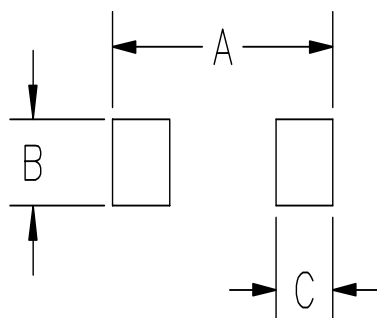
8 X 20us Pulse Waveform

SOD-323 Package Outline Drawing



SYM	DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.50	1.80	0.060	0.071
B	1.20	1.40	0.045	0.054
C	2.30	2.70	0.090	0.107
D	-	1.10	-	0.043
E	0.30	0.40	0.012	0.016
F	0.10	0.25	0.004	0.010
H	-	0.10	-	0.004

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
A	3.15	0.120
B	0.80	0.031
C	0.80	0.031